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Reg. No. : Name :

Fifth Semester B.Sc. Degree Examination, October 2015 First Degree Programme under CBCSS PHYSICS **Core Course VII** PY 1543 : Electronics

Time: 3 Hours

Max. Weight: 30

SECTION-A

This Section contains four Bunches each of four questions. Answer all questions. Each bunch carries a Weightage of one.

BUNCH-I

- 1. A semiconductor that is electrically neutral has
 - a) No majority carrier
 - b) No minority carrier
 - c) No free charges
 - d) Equal Number of positive and negative charges
- 2. By introducing a CLC filter to a full wave rectifier circuit, The ripple factor of the output gets
 - a) increased b) reduced c) unpredictable d) no change
- 3. When forward biased an ideal PN junction diode will act as a
 - a) current source b) open switch
 - c) closed switch d) emitter .
- 4. Out of the three regions of a transistor _____ region is heavily doped than other two.
 - a) base

b) collector c) emitter d) no

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c) Silicon dioxide

BUNCH-II

5.	Point of intersection of ac a) operating point c) cutoff region		b)	called active region knee voltage				
6.	In CB configuration of a transistor.a) collector and basec) collector and emitter	ransistor output	b)	aken between emitter and ba earth and base	se			
7.	In a Push-Pull amplifier, e a) A	each transistor ac b) B		as class C	d) AB			
8.	An emitter follower amplit a) Voltage series c) Current series	ier is a	b)	amplifier. Voltage shunt Current shunt				
BUNCH – III								
9.	In a Crystal oscillator quartz crystal is used toa) replace tank circuitb) replace feed back circuitc) stabilize frequencyd) increase bandwidth							
10.	Slope detection techniqua a) FM	e is used to demo b) AM		ate PM	signals. d) Both AM and FM			
11.	Compared to AM, FM tran a) narrower	nsmission require b) wider			_bandwidth. d) double sided			
12.	A device which turns on a voltage is exceeded is a) SCR	nd conducts curr		in either directi	on when break over d) Both b and c			
BUNCH – IV								
13.	 The Gate terminal of a MOSFET is isolated from the semiconductor by a the layer of 							
	a) Germanium	and an	b)	Silicon	aido			

d) Gallium Arsanide

14. In the active region of operation of a MOSFET the drain current I_d is a function of a) V_{GS} b) V_{DS} c) V_{CB} d) V_{CE}

15.	. Input resistance for an ideal OP-AMP is						
	a) zero	b) infinity	c) unity	d) less than zero			
16.	Voltage gain for an idea		A transition has a				
	a) zero	b) infinity	c) unity	d) less than zero			

SECTION - B

Answer any eight questions. Each question carries a Weightage of one.

- 17. Mention two types of extrinsic semiconductors and how do the differ in charge carriers ?
- 18. What is rectifier efficiency? What is its maximum value for a half wave rectifier?
- 19. PIV is important factor in selecting a diode for rectification. Why?
- 20. What is an emitter follower? What is its use in electronics?
- 21. Write the advantages of biasing an NPN transistor in base resister method.
- 22. Explain the term inter-modulation distortion in multistage amplifier.
- 23. What are the advantages of FM over AM ?
 - 24. Mention any 2 applications of a Triac.
 - 25. What is meant by Pinch off voltage?
 - 26. Why BJT is called a bipolar device while FET is called unipolar device ?
 - 27. What is meant by slew rate of an opamp?
 - 28. What is the significance of CMRR when selecting an OP-AMP?

SECTION-C

Answer any five questions. Each question carries a Weightage of two.

- 29. A zener diode of break down voltage 6.2V is used to regulate an input voltage that fluctuates between 9V and 12V. It is connected across a load of $1K\Omega$ and a series resistor of 330Ω . Calculate the maximum value of zener current.
- 30. A transistor has $\alpha = 0.98$ and $I_B = 100 \,\mu A$ and $I_{CO} = 6 \,\mu A$. Calculate I_C and I_E .
- 31. In a common emitter transistor amplifier when the signal changes by 0.02V, the base current changes by 10 μA and collector current changes by 1mA. Find current gain and input impedance.
- 32. A transistor in CE configuration has $h_{fe} = 110$ and $h_{ie} = 1K\Omega$ respectively. It is used as a single stage amplifier for amplifying low voltage signal with a collect load of $2.2K\Omega$. Calculate its current gain voltage gain and input resistance.
- 33. Find the operating frequency of a colpitts occilator if $C_1 = .005 \,\mu\text{F}$, $C_2 = .01 \,\mu\text{f}$ and $L = 10 \,\mu\text{H}$.
- 34. A differential amplifier has a typical common mode gain of 35 dB and CMRR of 72dB. Find the output voltage when 16mV is applied to inverting terminal and 18mV is applied to non-inverting terminal.
- 35. The maximum peak to peak voltage of an AM wave is 16mV while the minimum peak to peak voltage is 8mV. Find the percentage of modulation.
- 36. Drain current of an FET changes from 1mA to 1.4mA when its gate source voltage changes form -3V to -3.1V, while the drain source voltage remains unchanged. Calculate the trans conductance of the FET.

SECTION - D

Answer any two questions. Each question carries a Weightage of four.

- 37. With the help of neat diagram explain voltage current characteristics of a PN junction silicon diode. Derive an expression connecting forward dynamic resistance and current through the diode.
- 38. Mention the advantages and disadvantages of negative feed back amplifiers.
- 39. With the help of neat diagram and theory explain how an OP-AMP can be converted into a summing amplifier.